

Spin-dependent recombination and hyperfine interaction at the deep defects

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We present a theoretical study of optical electron-spin orientation and spin-dependent Shockley–Read–Hall recombination taking into account the hyperfine coupling between the bound-electron spin and the nuclear spin of a deep paramagnetic center. We show that the number of master rate equations for the components of the electron-nuclear spin-density matrix is considerably reduced due to the restrictions imposed by the axial symmetry of the system under consideration. The rate equations describe the Zeeman splitting of the electron spin sublevels in the longitudinal magnetic field, the spin relaxation of free and bound electrons, and the nuclear spin relaxation in the two defect states, with one and two (singlet) bound electrons. The general theory is developed for an arbitrary value of the nuclear spin I , the magnetic-field and excitation-power dependencies of the electron and nuclear spin polarizations are calculated for the particular value of $I = 1/2$. The role of the nuclear spin relaxation in each of the both defect states is analyzed. The circular polarization and intensity of the edge photoluminescence as well as the dynamic nuclear spin polarization as functions of the excitation power are shown to have bell-shaped forms.

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I. INTRODUCTION

Spin-dependent recombination (SDR) via deep paramagnetic centers has recently attracted increased interest and proved to be an effective tool for obtaining an abnormally high spin polarization of free and bound electrons in nonmagnetic semiconductor alloys $\text{GaAs}_{1-x}\text{N}_x$, $\text{Ga}_{1-y}\text{In}_y\text{As}_{1-x}\text{N}_x$ and semiconductor quantum wells Ga(In)AsN/GaAs at room temperature [1–6], see also [7] and references therein. The centers occupied by single spin-polarized electrons act as a spin filter [7–9] and block the free electrons of the same spin polarization from escaping from the conduction band. As a result the spin polarization of free photoelectrons generated by circularly polarized optical excitation (as well as that of bound electrons) can be enhanced up to $\sim 100\%$. The amplification of spin polarization is accompanied by an increase in the concentration of photoelectrons, the intensity of band-to-band photoluminescence (PL) and the photoconductivity, as compared to the linearly polarized photoexcitation [1, 3, 4, 10].

The hyperfine interaction between the localized electron and the nucleus of the deep center mixes their spin states resulting in (i) a reduction of the initial electron spin polarization and (ii) dynamic nuclear polarization of the defect atoms [11]. In the absence of an external magnetic field, the localized-electron spin polarization can be reduced down to $1/2$ and $3/8$ for the nuclear spin $I = 1/2$ and $3/2$, respectively. The longitudinal magnetic field suppresses the hyperfine coupling and restores the electronic polarization as soon as the electron Zeeman energy exceeds the hyperfine interaction: The expected increase in the intensity and circular polarization of the edge PL in the longitudinal magnetic field has been confirmed experimentally. In addition, strong nuclear polarization effects, due to a combination of the spin-dependent recombination and hyperfine coupling, have been reported and discussed in Refs. [12–19]. Particularly, the dynamically polarized nuclei create an effective magnetic field (the Overhauser field) acting on the spins of localized electrons; this field is added to the external magnetic field and shifts the ‘electron polarization vs. field’ curve, with the shift changing the sign under reversal of the circular polarization of the exciting light [13, 14, 17].

The theory of spin-dependent Shockley–Read–Hall recombination derived in Ref. [2], see for more details [7], ignores the nuclear effects. It has been successfully applied to describe the main features of optical spin orientation of conduction-band and deep-level electrons in

GaAsN at zero and transverse magnetic field $\mathbf{B} \perp z$, where the axis z is parallel to the exciting light beam and coincides with the normal to the sample surface. The model of Ref. [2] is unable to interpret the experimental data obtained in the longitudinal magnetic field $\mathbf{B} \parallel z$. The initial way out [13] was to assume the spin-relaxation time τ_{sc} of bound electrons to depend on the magnetic field B_z . This assumption could explain the polarization recovery with increasing the field but faced with the pressing need to find a mechanism of the field dependence of τ_{sc} which looked unresolvable. Moreover, the modified model cannot provide a reasonable interpretation of the observed shift of the polarization-field curve changing the sign under the reversal of circular polarization of the incident light.

The first attempt to give a theoretical description of the studied nuclear polarization processes has been performed by Puttison *et al.*, see Supplementary Methods for Ref. [17]. In that work, the hyperfine interaction is taken into account approximately by introducing magnetic-field-independent flip-flop processes in the electron-nuclear system and including an additional phenomenological parameter, the flip-flop spin relaxation time. This approximation obviously provides physical insight into the role of the nuclei but its validity for a quantitative description is not obvious. A kinetic theory of the spin-dependent recombination incorporating the hyperfine interaction of electronic and nuclear spins has been proposed recently by Sandoval-Santana *et al.* [19] The master equation approach for the spin-density matrix of the electron-nuclear system includes 144 equations which are solved numerically. The numerical calculation reproduces the main experimental findings of Ref. [14]. Nevertheless, the role of spin relaxation of nuclei in the system under consideration still remains open. In Ref. [19] the nuclear spins are polarized only in the deep-center states with single bound electrons. The nuclei with two bound electrons are characterized just by their steady state average concentration N_2 . This means nothing more than that the formulation of Ref. [19] is based on the assumption of very fast nuclear spin relaxation in the defect state with a pair of electrons. As far as we know, at present there are no grounds to take this assumption for granted. In general the spin relaxation times $\tau_n^{(1)}$ and $\tau_n^{(2)}$ for defect states with one and two bound electrons can be of the same order and even longer than the lifetimes of these states. In this work we develop a theory of the spin-dependent recombination and hyperfine coupling for the arbitrary values of $\tau_n^{(1)}$ and $\tau_n^{(2)}$. The paper is organized as follows. In Sec. II we introduce the electron-nuclear spin-density matrix of the defect state with a single bound electron and the spin-density matrix of the defect with two bound electrons (in the singlet

state) and discuss the restrictions imposed on the nonzero components of these matrices by the axial symmetry of the system in the longitudinal magnetic field. In Sec. III, we derive the rate equations for the spin density matrices taking into account both the hyperfine coupling for a nucleus with the angular momentum I and the electron and nuclear spin relaxation. The particular limiting cases are analyzed in Secs. III A, B and C. The simplifications in the case of a nucleus with $I = 1/2$ are considered in Sec. IV. The results of numerical calculation and their discussion are presented in Sec. V. Section VI contains the concluding remarks.

II. ELECTRON-NUCLEAR SPIN-DENSITY MATRIX

We use the basic states $|s, m\rangle$ of the electron-nuclear system, where $s = \pm 1/2$ and m ($-I \leq m \leq I$) are the bound-electron and nuclear spin projections upon the fixed axis z , hereafter the normal to the sample surface, and I is the angular momentum of a nucleus. In the first, general, part of the paper we will take I to be arbitrary and then shift to the particular case of $I = 1/2$ which allows simplification of the kinetic equations for the densities and spin polarizations of the free and bound electrons. For the deep defect responsible for the spin-dependent recombination in $\text{GaAs}_{1-x}\text{N}_x$, the momentum I is $3/2$. A detailed analysis for this value of I will be performed elsewhere.

In addition to $|s, m\rangle$, we also use the notation $|s, M - s\rangle$ for the state with the electron spin s and the total component of the angular momentum $M = s + m$. In the following we take into account the hyperfine interaction of the electron and nuclear spins given by the Fermi contact Hamiltonian

$$\mathcal{H}_{\text{hf}} = A \mathbf{s} \cdot \mathbf{I},$$

where s_α and I_α ($\alpha = x, y, z$) are the electron and nuclear spin operators. Moreover, we consider the normal incidence of the polarized exciting light in the external magnetic field $\mathbf{B} \parallel z$ (Faraday geometry), take into account the Zeeman Hamiltonian $\mathcal{H}_B = g\mu_B B_z s_z$ for the bound electrons and neglect the interaction between the magnetic field and the magnetic moments of the nuclei or conduction-band electrons. Here the bound-electron Landé factor $g \approx 2$ and μ_B is the Bohr magneton.

The occupation of the defect with one bound electron is described by a $2(2I+1) \times 2(2I+1)$ spin-density matrix $\rho_{sm,s'm'}$. In the Faraday geometry, the components with unequal total angular-momentum components $M = s + m$ and $M' = s' + m'$ vanish. Therefore, it is

enough to consider the components

$$\rho_{s,M-s;s',M-s'} \equiv \rho_{ss'}^{(M)}, \quad (1)$$

which are normalized on the density of single-electron defects

$$\sum_{s,m} \rho_{sm,sm} = \sum_{sM} \rho_{ss}^{(M)} = N_1.$$

The matrix $\rho_{ss'}^{(M)}$ with $M = I + 1/2$ or $M = -(I + 1/2)$ contains only one non-zero component and can be presented as

$$\rho_{ss'}^{(I+1/2)} = \delta_{ss'} \delta_{s,1/2} \rho_{1/2,I;1/2,I} \text{ and } \rho_{ss'}^{(-I-1/2)} = \delta_{ss'} \delta_{s,-1/2} \rho_{-1/2,-I;-1/2,-I}.$$

It is worth to note that the electron spin-density matrix (2×2 matrix)

$$\rho_{ss'}^e = \sum_M \rho_{ss'}^{(M)} \quad (2)$$

is diagonal whereas the matrices $\rho_{ss'}^{(M)}$ with $|M| < I + 1/2$ contain off-diagonal components. In the geometry under consideration, the spin-density matrix of the defect singlet with two bound electrons is diagonal, its $2I + 1$ diagonal components $N_{2,m}$ are normalized on the density of double-electron defects, N_2 . The sum of N_1 and N_2 gives the density of deep defects, N_e .

Thus, for a nucleus with $I = 3/2$, instead of 144 equations declared in Ref. [19] there are only 21 nonzero quantities to be found: 2 components $\rho_{1/2,1/2}^{(2)}$ and $\rho_{-1/2,-1/2}^{(-2)}$, 12 components $\rho_{s,s'}^{(M)}$ with $M = 0, \pm 1$ and $s, s' = \pm 1/2$, four components $N_{2,m}$ with $m = \pm 3/2, \pm 1/2$, the densities of electrons $n_{\pm 1/2} \equiv n_{\pm}$ in the conduction band with the spin $\pm 1/2$ and the unpolarized free-hole density p .

III. KINETIC EQUATIONS FOR THE SPIN-DENSITY MATRIX

The two kinetic equations

$$2c_n N_- n_+ + \frac{n_+ - n_-}{2\tau_s} = G_+, \quad (3)$$

$$2c_n N_+ n_- + \frac{n_- - n_+}{2\tau_s} = G_- \quad (4)$$

have the same form as those in the model of Ref. [7] where the hyperfine coupling was ignored. Here $N_+ = \rho_{1/2,1/2}^e$ and $N_- = \rho_{-1/2,-1/2}^e$ are the densities of single-electron defects

with the electron spin $\pm 1/2$, their sum $N_+ + N_-$ being N_1 , G_+ and G_- are the generation rates of the spin-up and spin-down photoelectrons, and c_n is the proportionality constant in the electron trapping rate by deep centers. We remind that, due to the relations

$$N_+ + N_- + N_2 \equiv N_1 + N_2 = N_c, \quad (5)$$

$$p = n + N_2, \quad n = n_+ + n_-, \quad (6)$$

among the four densities n, N_1, N_2 and p only two are linearly independent.

The steady-state kinetics of paired defects is described by the $2I + 1$ equations

$$\left(\dot{N}_{2,m} \right)_{\text{cb}} + \left(\dot{N}_{2,m} \right)_{\text{vb}} + \left(\dot{N}_{2,m} \right)_{\text{sr}} = 0. \quad (7)$$

The first term

$$\left(\dot{N}_{2,m} \right)_{\text{cb}} = 2c_n \left(n_- \rho_{\frac{1}{2}, \frac{1}{2}}^{(m+\frac{1}{2})} + n_+ \rho_{-\frac{1}{2}, -\frac{1}{2}}^{(m-\frac{1}{2})} \right)$$

describes generation of the defect states with two electrons due to the capture of a conduction-band electron onto a single-electron defect. The second term

$$\left(\dot{N}_{2,m} \right)_{\text{vb}} = -c_p p N_{2,m}$$

describes the recombination of a free unpolarized photohole with one of the singlet-state electrons, c_p is the proportionality constant. The final term describes the nuclear spin relaxation. For the nuclei with $I = 1/2$ it has a simple unambiguous form

$$\left(\dot{N}_{2,m} \right)_{\text{sr}} = -\frac{N_{2,m} - N_{2,-m}}{2\tau_n^{(2)}} = -\frac{1}{\tau_n^{(2)}} \left(N_{2,m} - \frac{N_2}{2} \right). \quad (8)$$

In case of the nucleus $I = 3/2$, the spin-relaxation term is ambiguous. However, if the perturbation leading to the inter-sublevel mixing is nonselective then, similarly to Eq. (8), the relaxation for $I = 3/2$ is characterized by one time parameter as follows [11]

$$\left(\dot{N}_{2,m} \right)_{\text{sr}} = -\frac{1}{\tau_n^{(2)}} \left(N_{2,m} - \frac{1}{2I+1} \sum_{m'} N_{2,m'} \right) = -\frac{1}{\tau_n^{(2)}} \left(N_{2,m} - \frac{N_2}{2I+1} \right). \quad (9)$$

The kinetic equations for the spin-density matrices $\rho_{ss'}^{(M)} = \rho_{sm,s'm'} (s+m = s'+m' = M)$ can be written in the compact form as

$$\dot{\rho}_{\text{cb}}^{(M)} + \dot{\rho}_{\text{vb}}^{(M)} + \dot{\rho}_{\text{esr}}^{(M)} + \dot{\rho}_{\text{nsr}}^{(M)} = \frac{i}{\hbar} [\mathcal{H}^{(M)} \hat{\rho}^{(M)}]. \quad (10)$$

In Eq. (10) the first and second terms

$$\left(\dot{\rho}_{ss'}^{(M)}\right)_{\text{cb}} = -c_n(n_{-s} + n_{-s'})\rho_{ss'}^{(M)}, \quad \left(\dot{\rho}_{ss'}^{(M)}\right)_{\text{vb}} = \frac{c_p}{2}N_{2,M-s}p\delta_{ss'} \quad (11)$$

describe the capture and loss of the second electron by a defect. The term on the right-hand side represents the hyperfine and Zeeman interactions with a 2×2 M -dependent spin Hamiltonian

$$\mathcal{H}^{(M)} = \hbar(u_M s_z + v_M s_x), \quad u_M = \beta + M\Omega, \quad v_M = \Omega \sqrt{\left(I + \frac{1}{2}\right)^2 - M^2},$$

where $\Omega = A/\hbar$, $\beta = g\mu_B B_z/\hbar$, $s_\alpha = \sigma_\alpha/2$ and σ_α are the spin Pauli matrices. The bound-electron spin relaxation is phenomenologically described by the standard term

$$\left(\dot{\rho}_{sm;s'm'}\right)_{\text{esr}} = -\frac{1}{\tau_{sc}} \left(\rho_{sm;s'm'} - \frac{\delta_{ss'}}{2} \sum_{s''} \rho_{s''m;s''m'} \right)$$

which is equivalent to

$$\left(\dot{\rho}_{ss'}^{(M)}\right)_{\text{esr}} = -\frac{1}{\tau_{sc}} \left[\rho_{ss'}^{(M)} - \frac{\delta_{ss'}}{2} \left(\rho_{ss}^{(M)} + \rho_{-s,-s}^{(M-2s)} \right) \right]. \quad (12)$$

Similarly to Eqs. (8) and (9), the nuclear spin relaxation can simply be described by

$$\left(\dot{\rho}_{sm;s'm'}\right)_{\text{nsr}} = -\frac{1}{\tau_n^{(1)}} \left(\rho_{sm;s'm'} - \frac{\delta_{mm'}}{2I+1} \sum_{m''} \rho_{sm'';sm''} \right), \quad (13)$$

or, see Eq. (2),

$$\left(\dot{\rho}_{ss'}^{(M)}\right)_{\text{nsr}} = -\frac{1}{\tau_n^{(1)}} \left(\rho_{ss'}^{(M)} - \delta_{ss'} \frac{\rho_{ss}^e}{2I+1} \right). \quad (14)$$

We remind that, for nonzero density-matrix components, the sum $s + m$ coincides with $s' + m'$ which means that $s = s'$ if $m = m'$. The set of equations (10) represents $8I + 2$ scalar equations, particularly, 6 equations for $I = 1/2$ and 14 equations for $I = 3/2$.

The summation of the terms in Eq. (10) over M yields the equations for the densities $N_\pm$ of single-electron defects, see Eqs. (3) and (4),

$$\begin{aligned} 2c_n N_+ n_- + \frac{N_+ - N_-}{2\tau_{sc}} + \frac{i}{\hbar} \sum_M [\mathcal{H}^{(M)} \hat{\rho}^{(M)}]_{\frac{1}{2}, \frac{1}{2}} &= 0, \\ 2c_n N_- n_+ + \frac{N_- - N_+}{2\tau_{sc}} + \frac{i}{\hbar} \sum_M [\mathcal{H}^{(M)} \hat{\rho}^{(M)}]_{-\frac{1}{2}, -\frac{1}{2}} &= 0. \end{aligned} \quad (15)$$

The off-diagonal components of the spin-density matrix $\hat{\rho}^{(M)}$ can be expressed via the diagonal components

$$\rho_{\frac{1}{2}, -\frac{1}{2}}^{(M)} = \frac{i}{\hbar} \frac{\mathcal{H}_{\frac{1}{2}, -\frac{1}{2}}^{(M)} \left(\rho_{\frac{1}{2}, \frac{1}{2}}^{(M)} - \rho_{-\frac{1}{2}, -\frac{1}{2}}^{(M)} \right)}{c_n n + \frac{1}{\tau_{sc}} + \frac{1}{\tau_n^{(1)}} + \frac{i}{\hbar} \left(\mathcal{H}_{\frac{1}{2}, \frac{1}{2}}^{(M)} - \mathcal{H}_{-\frac{1}{2}, -\frac{1}{2}}^{(M)} \right)}. \quad (16)$$

Excluding the off-diagonal components we obtain for the diagonal components of the commutator in Eq. (10)

$$\frac{i}{\hbar} [\mathcal{H}^{(M)} \hat{\rho}^{(M)}]_{\frac{1}{2}, \frac{1}{2}} = \frac{i}{\hbar} \left(\mathcal{H}_{\frac{1}{2}, -\frac{1}{2}}^{(M)} \rho_{-\frac{1}{2}, \frac{1}{2}}^{(M)} - \rho_{\frac{1}{2}, -\frac{1}{2}}^{(M)} \mathcal{H}_{-\frac{1}{2}, \frac{1}{2}}^{(M)} \right) = U_M \left(\rho_{\frac{1}{2}, \frac{1}{2}}^{(M)} - \rho_{-\frac{1}{2}, -\frac{1}{2}}^{(M)} \right), \quad (17)$$

where

$$U_M = \frac{v_M^2 \tau_c}{2} \frac{1 + \tau_c / \tau_{sc} + \tau_c / \tau_n^{(1)}}{\left(1 + \tau_c / \tau_{sc} + \tau_c / \tau_n^{(1)} \right)^2 + u_M^2 \tau_c^2} \quad (18)$$

and

$$\tau_c = \frac{1}{c_n n}. \quad (19)$$

The factor U_0 is an even function of the longitudinal magnetic field whereas the factors U_M with $M \neq 0$ are asymmetric functions of B_z because

$$u_M^2 = (\beta + M\Omega)^2 = (g\mu_B B_z + MA)^2 / \hbar^2. \quad (20)$$

Under circularly-polarized photoexcitation the electron-nuclear states with M and $-M$ ($M \neq 0$) can be differently involved in the kinetics which is the main reason for the asymmetry of dependence $P_e(B_z)$ observed experimentally.

The expression (17) describing the effect of hyperfine interaction can be rewritten in the form

$$\frac{2\pi}{\hbar} \left(\frac{v_M}{2} \right)^2 \left(\rho_{\frac{1}{2}, \frac{1}{2}}^{(M)} - \rho_{-\frac{1}{2}, -\frac{1}{2}}^{(M)} \right) \frac{1}{\pi} \frac{\hbar / \tilde{\tau}_c}{(\hbar u_M)^2 + (\hbar / \tilde{\tau}_c)^2}, \quad (21)$$

allowing the interpretation in the spirit of Fermi's golden rule for the probability rate

$$W_{21} = \frac{2\pi}{\hbar} |V_{21}|^2 (f_1 - f_2) \delta(E_2 - E_1)$$

of the transition from the quantum state $|1\rangle$ to the state $|2\rangle$, where E_2 and E_1 are the energies of these states, f_2 and f_1 are their average occupations, V_{21} is the matrix element of the perturbation operator. In Eq. (21), the role of ideal δ -function is played by the smoothed δ -function with the damping

$$\frac{1}{\tilde{\tau}_c} = \frac{1}{\tau_c} + \frac{1}{\tau_{sc}} + \frac{1}{\tau_n^{(1)}}. \quad (22)$$

A. The model neglecting nuclear spin relaxation

If the nuclear spin relaxation is neglected then the set of kinetic equations reads

$$\begin{aligned} c_p N_{2,m} p &= 2c_n \left(n_- \rho_{\frac{1}{2}, \frac{1}{2}}^{(m+\frac{1}{2})} + n_+ \rho_{-\frac{1}{2}, -\frac{1}{2}}^{(m-\frac{1}{2})} \right), \\ 2c_n n_{-s} \rho_{ss}^{(M)} + U'_M \left(\rho_{ss}^{(M)} - \rho_{-s, -s}^{(M)} \right) + \frac{1}{2\tau_{sc}} \left(\rho_{ss}^{(M)} - \rho_{-s, -s}^{(M-2s)} \right) &= \frac{c_p}{2} N_{2, M-s} p, \end{aligned} \quad (23)$$

where

$$U'_M = \frac{1}{2\tau_c} \frac{v_M^2 \tau_c^2 [1 + (\tau_c/\tau_{sc})]}{[1 + (\tau_c/\tau_{sc})]^2 + u_M^2 \tau_c^2}.$$

We remind that, for $M = \pm(I + 1/2)$, the value of u_M vanish and, thus, U'_M is nonzero only for $|M| < I + 1/2$.

Surprisingly, the set (23) has a simple magnetic-field-independent solution

$$\begin{aligned} P_e &= \frac{n_+ - n_-}{n_+ + n_-} = \frac{P_i G T}{1 - \eta}, \quad P_c = \frac{N_+ - N_-}{N_+ + N_-} = \frac{T_c}{\tau_c} P_e, \\ \rho_{ss}^{(M)} &= C_I N_1 (1 + P_c)^{J+M} (1 - P_c)^{J-M}, \\ N_{2,m} &= 2C_I N_2 (1 + P_c)^{I+m} (1 - P_c)^{I-m}, \end{aligned} \quad (24)$$

where $G = G_+ + G_-$ is the total optical generation rate of photoelectrons into the conduction band (or, equivalently, photoholes into the valence band), $P_i = (G_+ - G_-)/(G_+ + G_-)$ is the initial degree of photoelectron spin polarization,

$$\eta = \frac{T T_c}{\tau \tau_c}, \quad \tau = \frac{1}{c_n N_1}, \quad \frac{1}{T} = \frac{1}{\tau_s} + \frac{1}{\tau}, \quad \frac{1}{T_c} = \frac{1}{\tau_{sc}} + \frac{1}{\tau_c},$$

and the time τ_c is defined by Eq. (19). The factor C_I is given by

$$C_I = \frac{P_c}{(1 + P_c)^{2I+1} - (1 - P_c)^{2I+1}}$$

and equals to 1/4 for $I = 1/2$ and to $[8(1 + P_c^2)]^{-1}$ for $I = 3/2$.

One can see that, for the steady-state solution (24), the values $\rho_{ss}^{(M)}$ and $\rho_{-s, -s}^{(M)}$ coincide. This means that, on the first hand, the diagonal components of the commutator in Eqs. (15), (16) and (17) are switched off as if the hyperfine interaction were absent and, on the other hand, the nuclei are spin-polarized and their spin polarizations in the single- and double-electron defect states coincide

$$\frac{\sum_s \rho_{sm, sm}}{N_1} = \frac{N_{2,m}}{N_2}.$$

Since in the steady state the term $U'_M \left(\rho_{ss}^{(M)} - \rho_{-s,-s}^{(M)} \right)$ in Eq. (23) vanishes the densities of conduction-band electrons, n , and double-electron defects, N_2 , satisfy equations independent of the hyperfine constant A and the magnetic field:

$$Y(Y + Z) = X, \quad (25)$$

$$\frac{1 - Y}{a} \left\{ Z - P_i^2 \left(\frac{\tau_s}{\tau_h^*} \right)^2 \frac{X^2 (Z + \tau^*/\tau_{sc})}{[Z + \tau^*/\tau_{sc} + (1 - Y)\tau_s/\tau_{sc}]^2} \right\} = X,$$

where $\tau^* = (c_n N_c)^{-1}$, $\tau_h^* = (c_p N_c)^{-1}$, $a = c_p/c_n$ and we use the dimensionless variables

$$X = \frac{G}{c_p N_c^2}, \quad Y = \frac{N_2}{N_c} = \frac{N_c - N_1}{N_c}, \quad Z = \frac{n}{N_c}. \quad (26)$$

In these notations the hole density p is given by $(Y + Z)N_c$. Equations (25) are identical to Eqs. (20) in Ref. [7] derived neglecting electron-nuclear hyperfine interaction.

B. The model assuming fast nuclear spin relaxation in the paired singlet

As an alternative limiting case, we assume the nuclear spin relaxation in the defect state with two electrons to be quite short and set

$$N_{2,m} = \frac{N_2}{2I + 1}$$

in Eq. (23) and, similarly to [11], ignore the nuclear spin relaxation in the single-electron defects. For convenience, we will first ignore the spin relaxation of bound electrons and then will extend the obtained result to allow for this relaxation. The solution for the spin-density matrix can be presented in the form

$$\rho_{\pm\frac{1}{2}, \pm\frac{1}{2}}^{(M)} = \frac{c_p p N_2}{2(2I + 1)c_n n} \frac{(1 \pm P_e)(1 + u_M^2 \tau_c^2) + v_M^2 \tau_c^2}{(1 - P_e^2)(1 + u_M^2 \tau_c^2) + v_M^2 \tau_c^2}. \quad (27)$$

Note that since $v_{\pm(I+1/2)} = 0$ the components $\rho_{ss}^{(I+1/2)}$ and $\rho_{ss}^{(-I-1/2)}$ reduce to a much simpler form

$$\rho_{\frac{1}{2}, \frac{1}{2}}^{(I+1/2)} = \frac{c_p p N_2}{2(2I + 1)c_n n(1 - P_e)}, \quad \rho_{-\frac{1}{2}, -\frac{1}{2}}^{(-I-1/2)} = \frac{c_p p N_2}{2(2I + 1)c_n n(1 + P_e)}.$$

Moreover, the unphysical states with $s = 1/2, M = -(I + 1/2)$ and $s = -1/2, M = I + 1/2$ should be excluded from Eq. (27).

Using the identity

$$\frac{(1 \pm P_e)(1 + u_M^2 \tau_c^2) + v_M^2 \tau_c^2}{(1 - P_e^2)(1 + u_M^2 \tau_c^2) + v_M^2 \tau_c^2} = \frac{1}{1 \mp P_e} \left(1 \mp \rho_e \frac{v_M^2 \tau_c^2}{(1 - P_e^2)(1 + u_M^2 \tau_c^2) + v_M^2 \tau_c^2} \right),$$

we derive for the densities N_+ , N_- and the polarization degree P_c the following expressions

$$N_+ = \frac{1 - \zeta P_e}{2(1 - P_e)} G \tau_c, \quad N_- = \frac{1 + \zeta P_e}{2(1 + P_e)} G \tau_c, \quad P_c = \frac{1 - P_e}{1 - \zeta P_e} P_e, \quad (28)$$

where

$$\zeta = \frac{1}{2I + 1} \sum_M \frac{v_M^2 \tau_c^2}{(1 - P_e^2)(1 + u_M^2 \tau_c^2) + v_M^2 \tau_c^2}. \quad (29)$$

Replacing $N_{\pm}$ by their expressions (28) we find

$$P_e = \frac{P_i G \tilde{\tau}_s}{n} = \frac{P_i X \tilde{\tau}_s}{Z \tau^*}, \quad (30)$$

where

$$\frac{1}{\tilde{\tau}_s} = \frac{1}{\tau_s} + \zeta \frac{G}{n}.$$

The densities n and N_2 satisfy Eqs. (25) where

$$\tau_s^2 \frac{Z + \tau^*/\tau_{sc}}{[Z + \tau^*/\tau_{sc} + (1 - Y)\tau_s/\tau_{sc}]^2}$$

should be replaced by

$$\tau_s^{*2} = \frac{1 - \zeta}{1 - \zeta P_e^2} \frac{\tilde{\tau}_s^2}{Z}. \quad (31)$$

The spin relaxation of bound electrons can easily be incorporated into the balance equations if $\tau_{sc} \gg \tau_c$. For this purpose the sum in Eqs. (15) and (16) can be approximated by the sum calculated in the limit $\tau_{sc} \rightarrow \infty$ and given by $\zeta G P_e / 2$. As a result the problem is reduced to solving a set of four equations, namely, the two equations (3), (4) and two additional equations

$$\begin{aligned} 2c_n N_+ n_- + \frac{\zeta}{2} G P_e + \frac{N_+ - N_-}{2\tau_{sc}} &= \frac{c_p}{2} N_2 p, \\ 2c_n N_- n_+ - \frac{\zeta}{2} G P_e + \frac{N_- - N_+}{2\tau_{sc}} &= \frac{c_p}{2} N_2 p. \end{aligned} \quad (32)$$

It follows then that Eqs. (30) and (31) are valid as well if $\tilde{\tau}_s^{-1}$ is replaced by

$$\frac{1}{\tilde{\tau}_s} = \frac{1}{\tau_s} + \zeta \frac{G}{n} + \frac{N_1}{n} \frac{1}{\tau_{sc}} = \frac{1}{\tau_s} + \frac{\zeta X}{\tau_h^* Z} + \frac{1 - Y}{\tau_{sc} Z}. \quad (33)$$

One can see from Eqs. (31) and (33) that, for the fast spin relaxation of double-electron defect states, the hyperfine interaction effectively leads to a decrease of the electron spin relaxation time governed by the parameter ζ . Since ζ is an even function of B_z , see Eq. (29), in the approximation under consideration the point of minimum in the dependence $P_e(B_z)$ lies at $B_z = 0$.

C. Approximation of unpolarized nuclei

At low excitation powers when the lifetime of single-electron defect state $\tau_c = (c_n n)^{-1}$ is long compared with $\tau_n^{(1)}$ and that of two-electron states $\tau_{c2} = (c_p p)^{-1}$ is longer than $\tau_n^{(2)}$ one can take the nuclei to be unpolarized and set

$$\rho_{\pm\frac{1}{2},\pm\frac{1}{2}}^{(M)} = \frac{N_{\pm}}{2I+1}.$$

It follows then that the third terms describing in Eqs. (15) the hyperfine interaction can be replaced by

$$\frac{i}{\hbar} \sum_M [\mathcal{H}^{(M)} \hat{\rho}^{(M)}]_{\frac{1}{2},\frac{1}{2}} = -\frac{i}{\hbar} \sum_M [\mathcal{H}^{(M)} \hat{\rho}^{(M)}]_{-\frac{1}{2},-\frac{1}{2}} = \frac{N_+ - N_-}{2\tau_{scn}},$$

where τ_{scn}^{-1} is the bound-electron spin relaxation rate induced by the nucleus and defined by

$$\frac{1}{\tau_{scn}} = \frac{2}{2I+1} \sum_M U_M.$$

Therefore, in this approximation the influence of nuclei is accounted for by replacing τ_{sc}^{-1} by the sum $\tau_{sc}^{-1} + \tau_{scn}^{-1}$.

IV. HYPERFINE INTERACTION FOR A NUCLEUS WITH $I = 1/2$

In this case Eq. (7) reduces to two scalar equations for $N_{2,1/2}$ and $N_{2,-1/2}$ which can be transformed to the equations for $N_{2,1/2}$ and $N_2 = N_{2,1/2} + N_{2,-1/2}$:

$$\begin{aligned} c_p p N_{2,\frac{1}{2}} + \frac{1}{\tau_n^{(2)}} \left(N_{2,\frac{1}{2}} - \frac{N_2}{2} \right) &= 2c_n \left(n_- \rho_{\frac{1}{2},\frac{1}{2}}^{(1)} + n_+ \rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)} \right), \\ c_p p N_2 &= G. \end{aligned} \quad (34)$$

Equations (10) for $M = 0$ read

$$\begin{aligned} 2c_n n_- \rho_{\frac{1}{2},\frac{1}{2}}^{(0)} + \frac{i}{\hbar} [\mathcal{H}^{(0)} \hat{\rho}^{(0)}]_{\frac{1}{2},\frac{1}{2}} + \frac{\rho_{\frac{1}{2},\frac{1}{2}}^{(0)} - \rho_{-\frac{1}{2},-\frac{1}{2}}^{(-1)}}{2\tau_{sc}} + \frac{\rho_{\frac{1}{2},\frac{1}{2}}^{(0)} - \rho_{\frac{1}{2},\frac{1}{2}}^{(1)}}{2\tau_n^{(1)}} &= \frac{c_p}{2} N_{2,-\frac{1}{2}} p, \\ 2c_n n_+ \rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)} + \frac{i}{\hbar} [\mathcal{H}^{(0)} \hat{\rho}^{(0)}]_{-\frac{1}{2},-\frac{1}{2}} + \frac{\rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)} - \rho_{\frac{1}{2},\frac{1}{2}}^{(1)}}{2\tau_{sc}} + \frac{\rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)} - \rho_{-\frac{1}{2},-\frac{1}{2}}^{(1)}}{2\tau_n^{(1)}} &= \frac{c_p}{2} N_{2,\frac{1}{2}} p, \end{aligned} \quad (35)$$

where, see Eq. (17),

$$\frac{i}{\hbar} [\mathcal{H}^{(0)} \hat{\rho}^{(0)}]_{\frac{1}{2},\frac{1}{2}} = U_0 \left(\rho_{\frac{1}{2},\frac{1}{2}}^{(0)} - \rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)} \right). \quad (36)$$

Two additional equations for $\rho_{\frac{1}{2},\frac{1}{2}}^{(1)}$ and $\rho_{-\frac{1}{2},-\frac{1}{2}}^{(-1)}$ have the form

$$\begin{aligned} 2c_n n_- \rho_{\frac{1}{2},\frac{1}{2}}^{(1)} + \frac{\rho_{\frac{1}{2},\frac{1}{2}}^{(1)} - \rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)}}{2\tau_{sc}} + \frac{\rho_{\frac{1}{2},\frac{1}{2}}^{(1)} - \rho_{\frac{1}{2},\frac{1}{2}}^{(0)}}{2\tau_n^{(1)}} &= \frac{c_p}{2} N_{2,\frac{1}{2}} p, \\ 2c_n n_+ \rho_{-\frac{1}{2},-\frac{1}{2}}^{(-1)} + \frac{\rho_{-\frac{1}{2},-\frac{1}{2}}^{(-1)} - \rho_{\frac{1}{2},\frac{1}{2}}^{(0)}}{2\tau_{sc}} + \frac{\rho_{-\frac{1}{2},-\frac{1}{2}}^{(-1)} - \rho_{-\frac{1}{2},-\frac{1}{2}}^{(0)}}{2\tau_n^{(1)}} &= \frac{c_p}{2} N_{2,-\frac{1}{2}} p. \end{aligned} \quad (37)$$

From Eqs. (35) and (36) we conclude that the set of equations for the diagonal components of the spin-density matrix and occupations $N_{2,m}$ are dependent on the magnetic field through the square $u_0^2 = (g\mu_B B_z \tau_c / \hbar)^2$. This clearly demonstrates that, for $I = 1/2$, the electron spin polarization $P_e = (n_+ - n_-)/(n_+ + n_-)$ is a symmetric function of B_z and has a minimum at the point $B_z = 0$.

Equations (3)–(6), (34)–(37) form a complete set to be solved. It may be further converted for a more convenient numerical calculation. By using Eqs. (35) and (37) we can establish a linear relation

$$\rho_{s,s}^{(M)} = \frac{c_p p}{2c_n n} \sum_{m=\pm 1/2} Q_{s,m}^{(M)} N_{2,m} \quad (38)$$

between the components of spin-density matrix $\rho_{ss}^{(M)}$ and the densities $N_{2,\pm 1/2}$. The expressions for dimensionless coefficients $Q_{s,m}^{(M)}$ have a simple but cumbersome form and are not presented here. Substituting (38) into Eq. (34) we find $N_{2,\pm 1/2}$ and $f_m = N_{2,m}/N_2$. The next step is to write down expressions for the densities of single-electron defects with the electron spin $\pm 1/2$, namely,

$$N_+ = \sum_{M=0,1} \rho_{1/2,1/2}^{(M)} = N_2 \frac{c_p p}{2c_n n} D_{1/2}, \quad N_- = \sum_{M=-1,0} \rho_{-1/2,-1/2}^{(M)} = N_2 \frac{c_p p}{2c_n n} D_{-1/2}, \quad (39)$$

where the coefficients

$$D_{1/2} = \sum_m \sum_{M=0,1} Q_{1/2,m}^{(M)} f_m, \quad D_{-1/2} = \sum_m \sum_{M=-1,0} Q_{-1/2,m}^{(M)} f_m \quad (40)$$

are functions of n_+ , n_- and parameters of the model.

The substitution of (6), (39) into Eqs. (3), (4) gives us two equations connecting three unknown quantities n_+ , n_- and N_2 . We replace them by their sum and difference and obtain

$$Y(Y + Z) = X, \quad (41)$$

$$X P_i - \frac{\tau_h^*}{\tau_s} P_e Z = X F(P_e, Z), \quad (42)$$

where

$$F(P_e, Z) = \frac{1 + P_e}{2} D_{-1/2}(P_e, Z) - \frac{1 - P_e}{2} D_{+1/2}(P_e, Z) ,$$

and the dimensionless variables (26) are used. Note that Eq. (41) follows immediately from the second equation (34) and coincides with the first equation (25). To find the third equation we express N_+ , N_- via $n_{\pm}$ by using Eqs. (3), (4) and insert the expressions into Eq. (6) arriving at

$$X(1 - P_i P_e) + \frac{\tau_h^*}{\tau_s} P_e^2 Z = \frac{1 - Y}{a} (1 - P_e^2) Z , \quad (43)$$

where $a = c_p/c_n$ and hereafter, instead of $n_{\pm}$, we use the variables $n = n_+ + n_-$ and $P_e = (n_+ - n_-)/(n_+ + n_-)$.

From Eq. (43) one has

$$Y = 1 - a \frac{X(1 - P_i P_e) + (\tau_h^*/\tau_s) Z P_e^2}{Z(1 - P_e^2)} = \frac{L + MZ}{Z} , \quad (44)$$

where L, M are independent of Z . Therefore the substitution of (44) into Eq. (41) gives a third-order equation for Z . Two of the three solutions of this equation are positive and define the dependencies of electron concentration on P_e and X . These dependencies together with (42) allow to find two values of P_e at fixed photogeneration rate X , but one of the corresponding values of the density of double-electron defects Y turns out to be negative, and the solution of Eqs. (41)–(43) is unique.

If the nuclear spin relaxation is neglected or the hyperfine coupling is completely absent then Eqs. (42) and (43) reduce, respectively, to the first equation (24) and the second equation (25).

V. RESULTS OF COMPUTER CALCULATION AND DISCUSSION

The signature of the electron-nuclear hyperfine coupling in single-electron defect states is a growth of the spin polarization P_e of conduction-band electrons and the interband PL intensity J with increasing the longitudinal magnetic field as shown in Figs. 1(a), 1(b) and 1(c). In experiment this is observed, under circularly polarized interband optical excitation, via the magnetic-field induced increase in the PL circular polarization and intensity [13, 14, 16, 17, 19]. The set of parameters unrelated to the nuclei and hyperfine coupling is the same as used in the previous analysis [13]: $\tau^* = 2$ ps, $\tau_h^* = 30$ ps, $\tau_s = 140$ ps, $\tau_{sc} = 700$ ps, $P_i = 0.13$, $N_c = 3 \times 10^{15} \text{ cm}^{-3}$. For the deep centers in GaAsN the average hyperfine

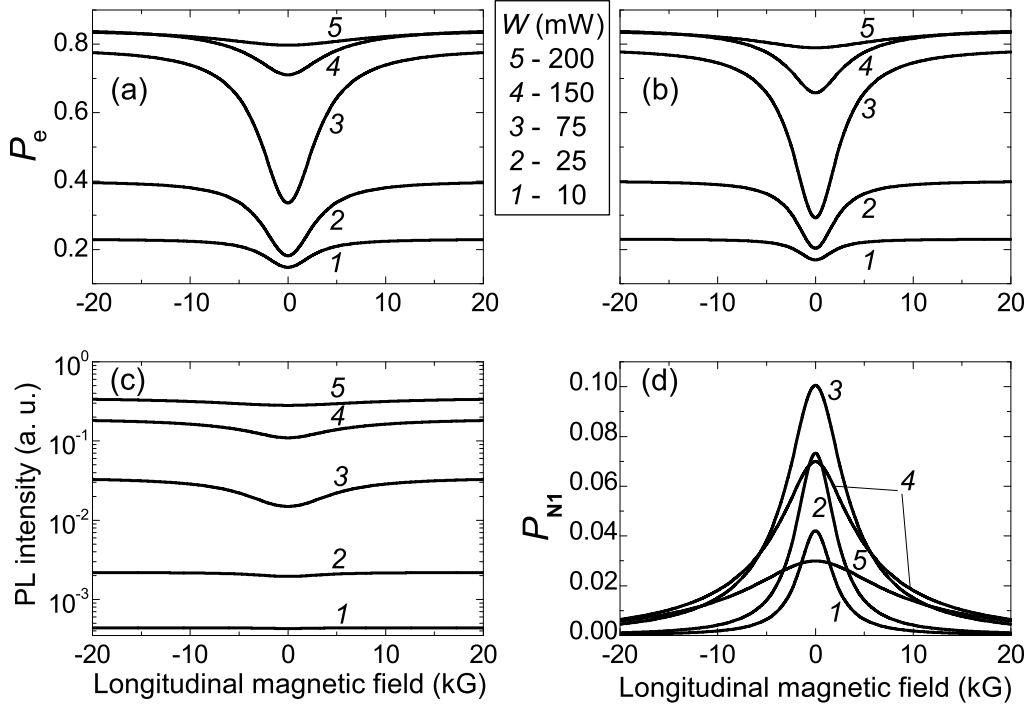


FIG. 1: Spin polarization degree of the conduction-band electrons (a,b), the intensity of interband PL (c) and nuclear spin polarization (d) as a function of the longitudinal magnetic field calculated for different excitation powers W of the circularly polarized light. The curves 1 – 5 correspond respectively to the following values of W : 10, 25, 75, 150, and 200 mW. The set of model parameters $\tau^* = 2$ ps, $\tau_h^* = 30$ ps, $\tau_s = 140$ ps, $\tau_{sc} = 700$ ps, $P_i = 0.13$, $N_c = 3 \times 10^{15} \text{ cm}^{-3}$, $A = 17 \mu\text{eV}$ is used in the calculation. The relation $G = 2 \times 10^{23} W$ between the generation rate and excitation power is derived from the experiment, the units for G and W are $\text{cm}^{-3}\text{s}^{-1}$ and mW, respectively. Panel (a): Both the nuclear spin relaxation time of the one-electron defect state ($\tau_n^{(1)}$) and that of the two-electron state ($\tau_n^{(2)}$) are taken to equal 150 ps. Panels (b), (c) and (d): $\tau_n^{(1)} = 1000$ ps, $\tau_n^{(2)} = 1$ ps. Surprisingly, the sets (a) and (b) of the calculated curves are qualitatively similar.

constant A was estimated as $6.9 \times 10^{-2} \text{ cm}^{-1} = 8.5 \mu\text{eV}$ [12, 18]. For the nucleus $I = 3/2$, the hyperfine splitting of the states with the total angular momenta 2 and 1 equals $2A$. To have a comparable strength of the hyperfine interaction with the nucleus $I = 1/2$ we take $A = 17 \mu\text{eV}$. The choice of the nuclear spin relaxation time in the single-electron defect state, $\tau_n^{(1)}$, causes the greatest difficulties. Apparently, this phenomenological time parameter cannot be shorter than the time $\tau_n^{(2)}$ describing spin relaxation of the nuclei in the two-electron

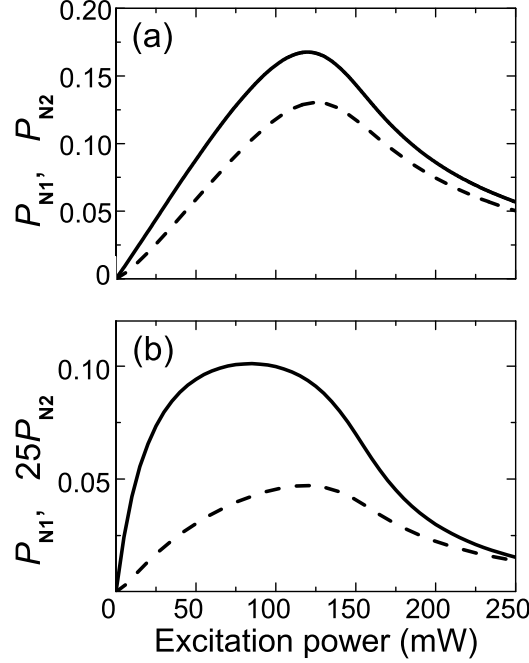


FIG. 2: Nuclear spin polarizations P_{N1} (solid curves) and P_{N2} (dashed) as a function of the excitation power calculated at zero magnetic field for (a) $\tau_n^{(1)} = \tau_n^{(2)} = 150$ ps and (b) $\tau_n^{(1)} = 1000$ ps, $\tau_n^{(2)} = 1$ ps. In panel (b) the values of P_{N2} are multiplied by the factor of 25.

defect states. The growth of the polarization P_e illustrated in Fig. 1 is calculated for (a) the coinciding times $\tau_n^{(1)}$ and $\tau_n^{(2)}$ and (b) for the short time $\tau_n^{(2)}$ and long time $\tau_n^{(1)}$. The nuclear spin polarization is characterized by the two polarization degrees

$$P_{N1} = \frac{1}{N_1} \sum_s \left(\rho_{s, \frac{1}{2}; s, \frac{1}{2}} - \rho_{s, -\frac{1}{2}; s, -\frac{1}{2}} \right), \quad P_{N2} = \frac{N_{2, \frac{1}{2}} - N_{2, -\frac{1}{2}}}{N_2}.$$

Their dependence on the excitation power W calculated in the absence of magnetic field is depicted in Fig. 2. In the case (a) the values P_{N1} and P_{N2} are different but comparable in magnitude whereas in the case (b), as expected, the polarization P_{N2} is small and the polarization P_{N1} is of the same order as the polarizations in Fig. 2(a). As seen in Fig. 1(d), the average nuclear spin is the highest at $B = 0$ and exhibits depolarization with the increasing magnetic field since the field decouples the electron and nuclear spins. It is also worth to note that the zero-field nuclear spin polarization is a nonmonotonic function of the excitation power and reaches a maximum for the intermediate power ~ 75 mW. This can be understood as follows: in the low-power limit, the system is slightly driven out of the equilibrium and the nuclear polarization is still weak; in the high-power limit, the lifetime of

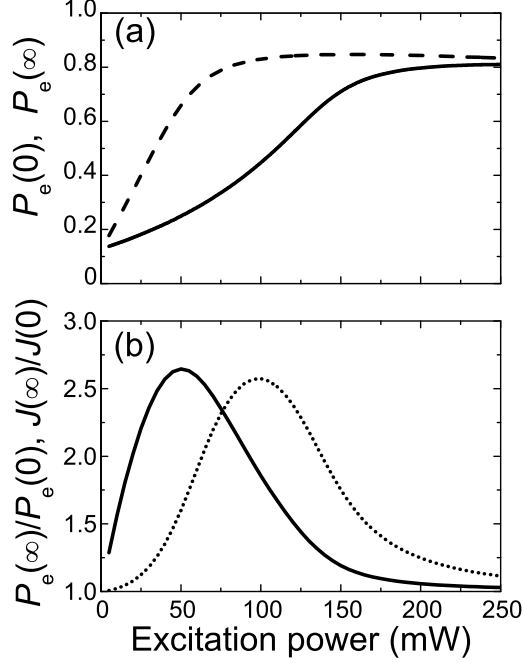


FIG. 3: (a) Spin polarization of the conduction-band electrons as a function of the excitation power calculated at zero magnetic field (solid curve) and infinitely high magnetic field (dashed curve). The parameters are the same as in Fig. 1(b). (b) The dependence of ratios $P_e(\infty)/P_e(0)$ (solid) and $J(\infty)/J(0)$ (dotted) on the excitation power.

bound electrons τ_c is very short, the hyperfine-coupling factor U_M in Eqs. (17), (18) decreases and the dynamic nuclear polarization by the polarized electrons is strongly weakened.

The spin-filtering effect is demonstrated in Fig. 3(a). At very low excitation intensity this effect is not switched on, the degree P_e is independent of the magnetic field and the two curves in the figure calculated at zero (solid) and infinitely high (dashed) magnetic field merge as $W \rightarrow 0$. At very high pumping the curves again merge since the lifetime $\tilde{\tau}_c$, see Eq. (22), becomes very short and the uncertainty caused by this reduction decouples the hyperfine interaction. Figure 3(b) shows the power dependence of the ratio of electron polarizations at the strong and zero magnetic fields (solid) and similar ratio of the PL intensities (dotted). The peaks of the two curves are shifted with respect to each other in agreement with the experiment, Fig. 4(b) in Ref. [13].

Figure 4 illustrates the sensitivity of the polarization P_e to variation of the nuclear spin relaxation time in the models with $\tau_n^{(1)} = \tau_n^{(2)}$ and $\tau_n^{(1)} \neq \tau_n^{(2)}$. It is clear from the figure that there exists a critical interval of the time values above which the electron polarization

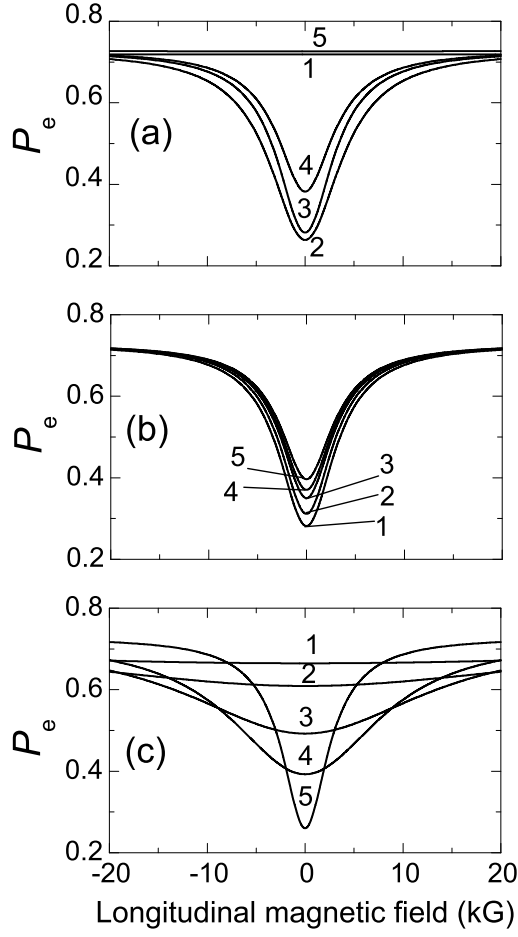


FIG. 4: Dependence of the spin polarization of the conduction-band electrons on the magnetic field calculated for the excitation power 60 mW and different values of the nuclear spin relaxation time $\tau_n^{(1)}$ (a) assuming $\tau_n^{(1)}$ and $\tau_n^{(2)}$ to coincide and being equal to 0.15 ps (curve 1), 50 ps (2), 150 ps (3), 450 ps (4), and 150000 ps (5); (b) keeping $\tau_n^{(2)} = 150$ ps fixed and $\tau_n^{(1)}$ taking the values 150 ps (curve 1), 300 ps (2), 750 ps (3), 1500 ps (4) and 150000 ps (5); and (c) $\tau_n^{(2)} = 1$ ps and $\tau_n^{(1)} = 1$ ps (curve 1), 2 ps (2), 5 ps (3), 10 ps (4), and 1000 ps (5). Other parameters are the same as in Fig. 1(b).

ceases to depend on the magnetic field confirming the conclusion of Sec. III A. The detailed calculation shows that this interval lies around 1000 ps. On the other hand, at extremely short nuclear spin relaxation times the magnetic field dependence of P_e disappears as well, due to the increasing uncertainty of $\tilde{\tau}_c^{-1}$ in Eqs. (21), (22).

Finally, Fig. 5 depicts the magnetic field dependence of P_e for different values of the hyperfine constant A . At zero A the electron polarization is insensitive to the longitudinal

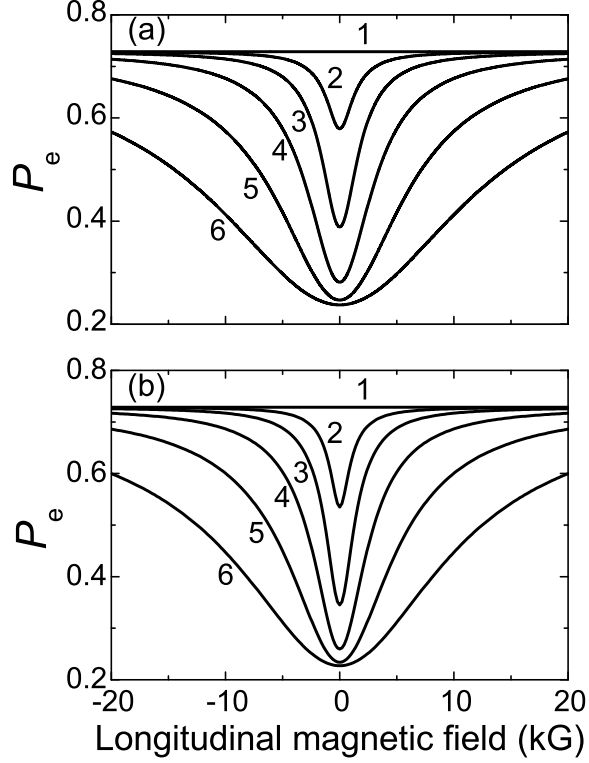


FIG. 5: Effect of the hyperfine interaction on the dependence of the spin polarization of the conduction-band electrons on the magnetic field. Curves 1 – 6 are calculated for the excitation power 60 mW and the following values of the hyperfine constant: $A = 0$ (horizontal line 1), $A_0/4$ (curve 2), $A_0/2$ (3), A_0 (4), $2A_0$ (5) and $4A_0$ (6), where $A_0 = 17 \mu\text{eV}$. Panel (a): $\tau_n^{(1)} = \tau_n^{(2)} = 150 \text{ ps}$; panel (b): $\tau_n^{(1)} = 1000 \text{ ps}$ and $\tau_n^{(2)} = 1 \text{ ps}$. The values of other parameters are the same as in Fig. 1.

magnetic field. With A increasing up to $68 \mu\text{eV}$ the zero-field value of P_e decreases by a factor of ~ 3 . The halfwidth B_{hw} of the recovery curve

$$\frac{P_e(B) - P_e(0)}{P_e(\infty) - P_e(0)}$$

increases sublinearly and is more sensitive to the variation of A as compared to $P_e(0)$.

VI. CONCLUSION

Thus, due the axial symmetry of the system in the external longitudinal magnetic field, the components $\rho_{sm,s'm'}$ of the spin-density matrix of the defect state with a single electron are nonzero only for the equal total angular momentum projections $M = s + m$ and $M' =$

$s' + m'$, and the spin-density matrix of the defect pair-singlet state is diagonal and described by the densities $N_{2,m}$ of the centers with the nuclear spin projection m . The off-diagonal components $\rho_{s,M-s;s',M-s'}$ with $s \neq s'$ can be readily expressed via the diagonal components which has allowed us to derive the quantum master equations containing only the diagonal components $\rho_{sm,sm}$ and $N_{2,m}$. The equations take into account the Zeeman splitting of the electron states in the longitudinal magnetic field, the electron-nuclear spin coupling described by the hyperfine constant A , the spin relaxation of free and bound electrons described respectively by the times τ_s and τ_{sc} , and the nuclear spin relaxation in the defect states with one and two electrons, respectively the times $\tau_n^{(1)}$ and $\tau_n^{(2)}$. The model reproduces the magnetic-field-induced suppression of the hyperfine interaction, the recovery of the electron spin polarization and the increase in the edge PL intensity under the circularly polarized optical excitation. It has been shown that for the nuclear spin $I = 1/2$ both the PL intensity and circular polarization are even functions of the longitudinal magnetic field B_z . Moreover, even for $I > 1/2$, there is no shift of polarization-field or intensity-field curve if the nuclear spin relaxation is negligible or too fast.

For $I = 1/2$ we have calculated the magnetic-field and excitation-power dependencies of the electron and nuclear spin polarizations and analyzed the role of the nuclear spin relaxation in each of the two defect states. The dynamic nuclear spin polarization appears to be a nonmonotonic function of the excitation power. Similarly, the ratios $P_e(\infty)/P_e(0)$ and $J(\infty)/J(0)$ of polarizations and PL intensities at infinitely high and zero magnetic fields have, as functions of the excitation power, bell-shaped forms with maxima shifted by several tens of mW with respect to each other.

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